

# Stability of Dirac cone in artificial graphene

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## What is the Artificial Graphene (AG) ?

It's an artificial material that exploits the properties of graphene in a tunable setup. Actually It has been realized 3 different physical implementations:

- 2D electron gas in a semiconductor heterostructures
- Metal surfaces shaped by molecules
- Trapped cold atoms in an optical lattice

## Benefits of using AG:

- Great spatial accuracy to better control Dirac Fermions
- Lattice constants from tenths nm to hundreds nm
- Alternative texturing, like Kekulé distortions

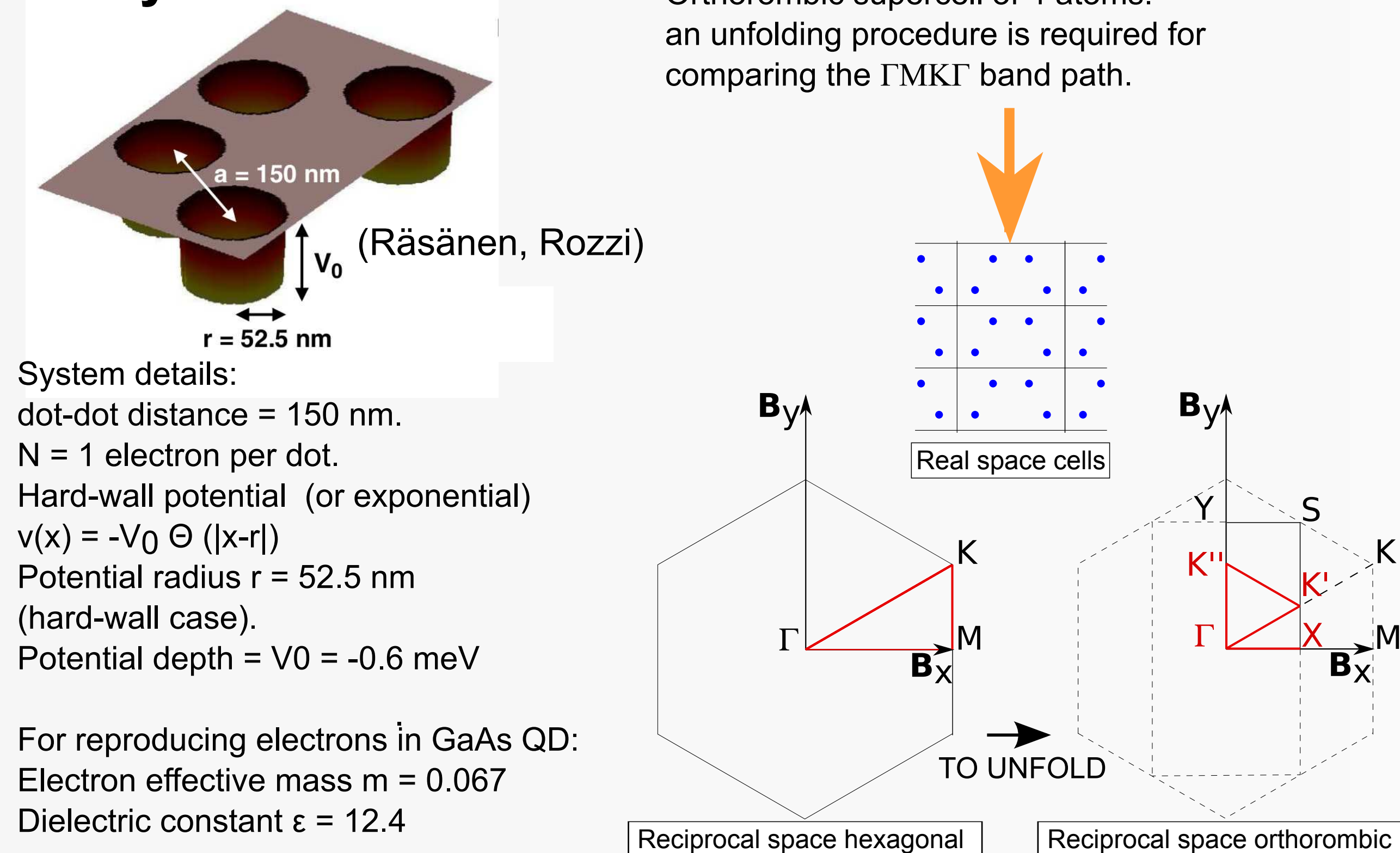
## Previous works:

- for electrons confined in GaAs quantum dots:
- Tight binding calculations of Gilbertini et al.[1] show graphene-like bands;
  - Confirmed by DFT results (Räsänen, Rozzi [2]).

## Present work

- Study of the stability of AG Dirac cone in GaAs QD with respect to changes in the following parameters:
- dots potential radius;
  - dislocations of atoms position;
  - lattice constant change.

## AG system studied



## Theory and computational method

2D system periodic in 2D.  
 Theory: independent particles (IP), DFT-LDA, DFT-mGGA  
 Bloch wavefunctions in real space (Octopus Code 4.0.1) [3]  
 Kohn-Sham equations with periodic boundary conditions.

Convergence parameters: - mesh spacing (0.2-0.3 effective bohr)  
 - number of k-points in the irreducible Brillouin zone (300-600).  
 Usage of Broyden mixing and symmetrization of the density.

LDA: Slater Exchange LDA (PAM Dirac) + AMGB correlation (Attaccalite) [4]  
 mGGA: exchange PRHG07 [5,6] + AMGB correlation (Attaccalite).

## Change of potential shape and dot radius

A possible improvement of the forementioned model of electrons in GaAs dots, can be obtained by the replacement of the hard-wall potential with a more realistic one of exponential shape, i.e. :

$$\text{Dot potential: } v_{dot}(r) = V_0 \exp\left(-\frac{r}{L}\right)^\alpha$$

We performed IP, LDA and mGGA calculations varying the exponent  $\alpha$  ( $=2,4,8,12$ ) and the effective radius  $L$  from 0.1 to 0.5 times the dot-dot distance  $a$  ( $=150$  nm).

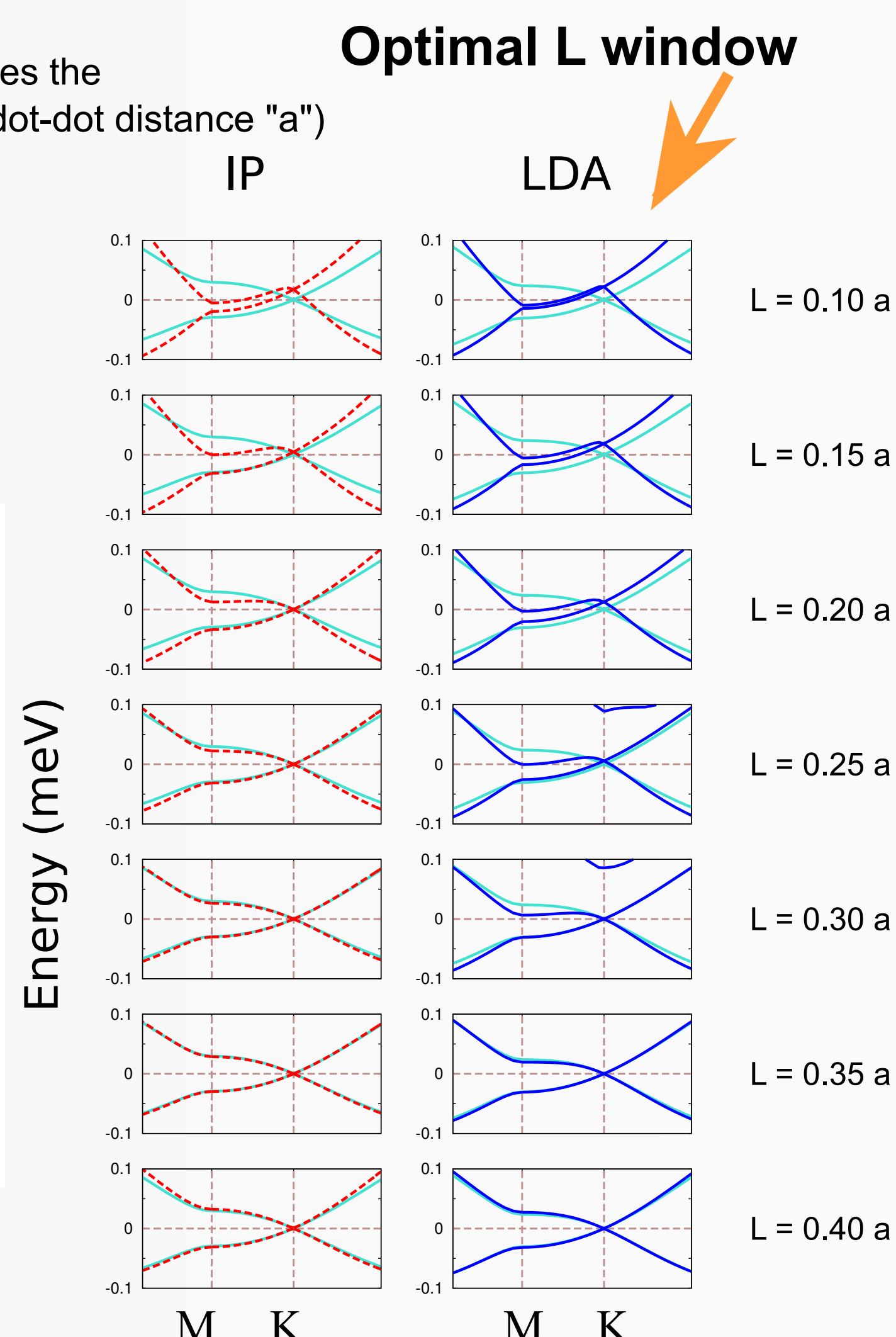
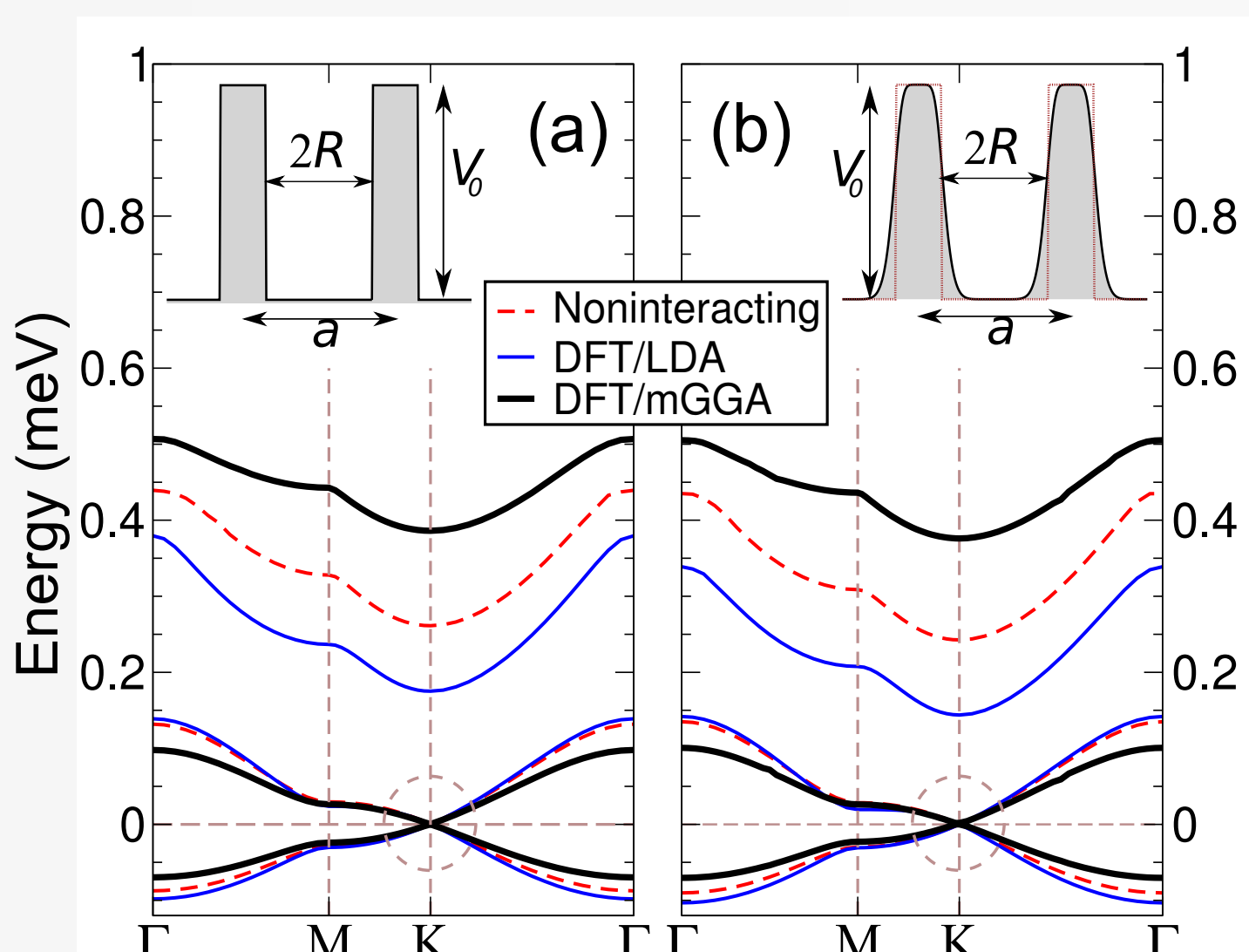
### Results:

- Little change occurs varying  $\alpha$ ;
- There is an optimal window of  $L$  values that optimizes the stability for all the calculations ( $[0.30, 0.40]$  times the dot-dot distance "a")

### Parameters of maximal stability:

$$\alpha = 8$$

$$L = 0.35a$$



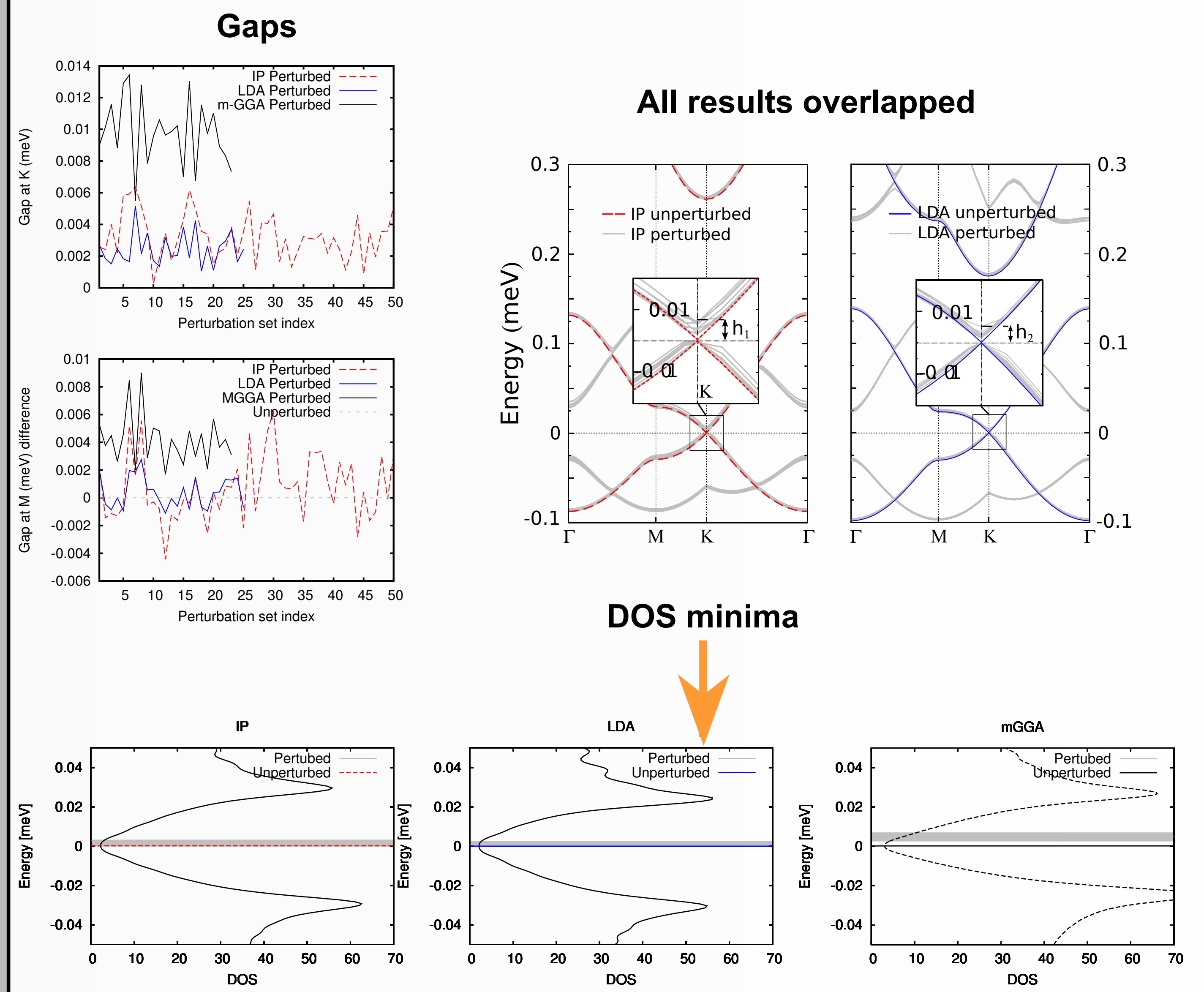
## Dislocation of atoms position.

We applied to all the atoms of the cell a dislocation with modulus  $0\%2$  of the dot-dot distance and with random angle in  $[0, 2\pi]$ .

- 50 random dislocation sets used for IP, 25 for LDA and 25 for mGGA.

### Results:

- There is always a gap opening but is always less than  $1.4 \times 10^{-2}$  meV.
- LDA shows the highest stability, DFT-mGGA is the less stable but its variation is of the same order of magnitude for the gaps at K and M and for the bands in general.
- The DOS minimum change is very small  $\rightarrow$  further stability.

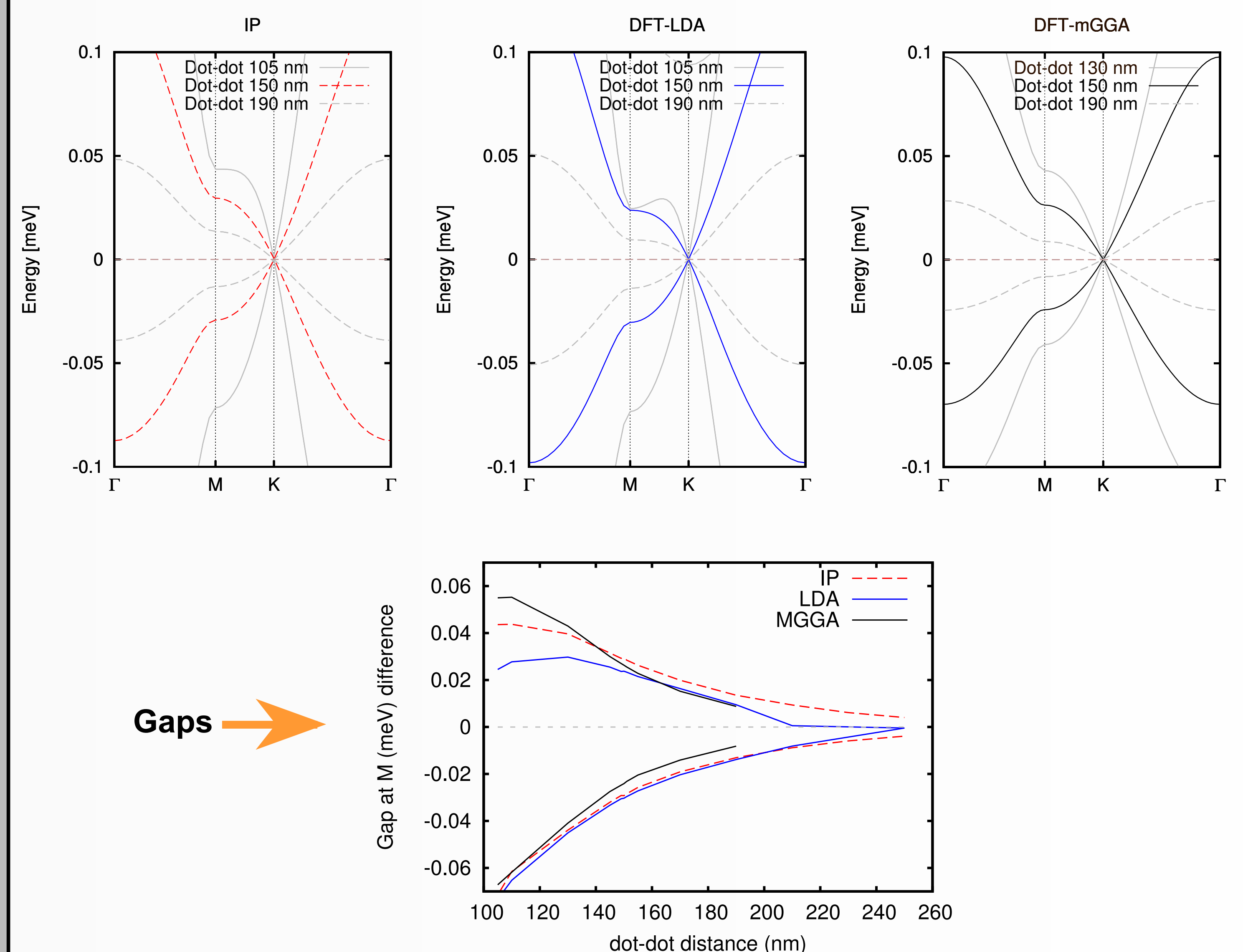


## Change of lattice constant

Dot-dot distance from 105 nm to 250 nm (till 190 for mGGA) and the Dirac cone is maintained.

### Results:

- We can see that the system experiences a transition towards metallicity for an increasing dot-dot distance
- The process is faster in presence of e-e interaction than for IP calculation.



## Future developments

- Spin polarized case
- Studying effect of repulsive potentials in triangular lattices instead of attractive potentials in honeycomb lattices
- Optical properties

## Bibliography

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